DESCRIPTION

The SPN1022 is the Dual N-Channel enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology. This high density process is especially tailored to minimize on-state resistance and provide superior switching performance. These devices are particularly suited for low voltage applications such as notebook computer power management and other battery powered circuits where high-side switching, low in-line power loss, and resistance to transients are needed.

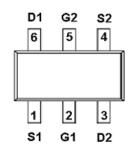
APPLICATIONS

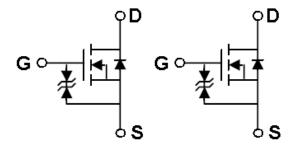
- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

FEATURES

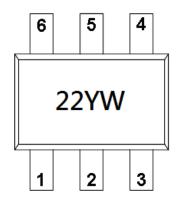
- N-Channel
 20V/0.65A,RDS(ON)=380mΩ@VGS=4.5V
 20V/0.55A,RDS(ON)=450mΩ@VGS=2.5V
 20V/0.45A,RDS(ON)=800mΩ@VGS=1.8V
- ◆ Super high density cell design for extremely low RDS (ON)
- ◆ Exceptional on-resistance and maximum DC current capability
- ♦ ESD protected
- ◆ SOT-563 (SC-89-6L) package design

PIN CONFIGURATION (SOT-563 / SC-89-6L)





PART MARKING



PIN DESCRIPTION							
Pin	Symbol	Description					
1	S1	Source 1					
2	G1	Gate 1					
3	D2	Drain 2					
4	S2	Source 2					
5	G2	Gate 2					
6	D1	Drain1					

ORDERING INFORMATION

Part Number	Package	Part Marking
SPN1022S56RGB	SOT-563	22

[※] SPN1022S56RGB: Tape Reel; Pb − Free, Halogen - Free

ABSOULTE MAXIMUM RATINGS

(TA=25°C Unless otherwise noted)

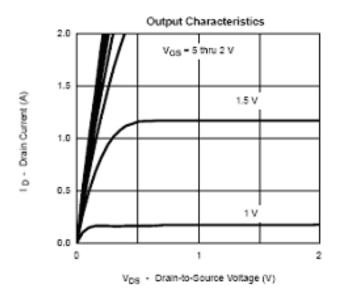
Parameter		Symbol	Typical	Unit	
Drain-Source Voltage		VDSS	20	V	
Gate –Source Voltage		VGSS	±12	V	
G .: D : G ./T 1500G)	Ta=25°C	In	0.65	Α.	
Continuous Drain Current(T _J =150°C)	Ta=80°C	ID	0.45	A	
Pulsed Drain Current		IDM	1.0	A	
Continuous Source Current(Diode Conduction)		Is	0.3	A	
D D' : .:	Ta=25°C	D-	0.35	W	
Power Dissipation	Ta=70°C	PD	0.19	W	
Operating Junction Temperature		Тл	-55/150	°C	
Storage Temperature Range		Tstg	-55/150	°C	

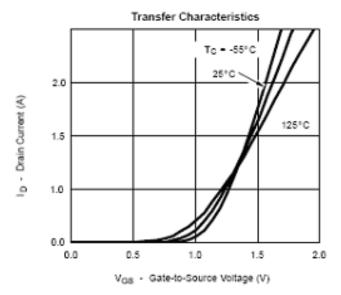
ELECTRICAL CHARACTERISTICS

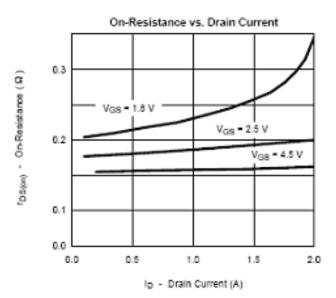
(TA=25°C Unless otherwise noted)

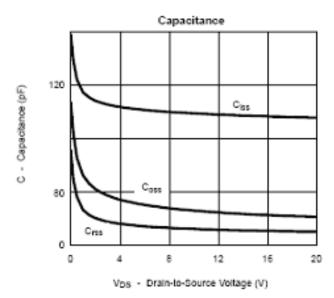
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit	
Static			•				
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V,ID=250uA	20			V	
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	0.35		1.0] '	
Gate Leakage Current	Igss	VDS=0V,VGS=±12V			10	uA	
		VDS=20V,VGS=0V			1	uA	
Zero Gate Voltage Drain Current	Idss	VDS= 20V,VGS=0V TJ=55°C			5		
On-State Drain Current	ID(on)	V _D s≥4.5V,V _G s =5V	0.7			A	
		Vgs=4.5V,Id=0.65A		0.26	0.38		
Drain-Source On-Resistance	RDS(on)	VGS=2.5V,ID=0.55A		0.32	0.45	Ω	
E	- f-	VGS=1.8V,ID=0.45A		0.42	0.80		
Forward Transconductance	gfs	VDS=10V,ID=0.4A		1.0		S	
Diode Forward Voltage	Vsd	Is=0.15A,VGS=0V		0.8	1.2	V	
Dynamic							
Total Gate Charge	Qg	V _{DS} =10V,V _{GS} =4.5V,		1.2	1.5	nC	
Gate-Source Charge	Qgs	ID=0.6A		0.2			
Gate-Drain Charge	Qgd			0.3			
Input Capacitance	Ciss			110			
Output Capacitance	Coss	VDS=16V,f=1MHz,		60		pF	
Reverse Transfer Capacitance	Crss	V _{GS} =0V		38			
-	td(on)	Van 10VD: 100		5	10	nS	
Turn-On Time	tr	-VDD= 10 V,RL= 10Ω , ID= 0.5 A		8	15		
T. OSST.	td(off)	$V_{GEN}=4.5V,R_{G}=6\Omega$		10	18		
Turn-Off Time	tf			1.2	2.8]	

TYPICAL CHARACTERISTICS

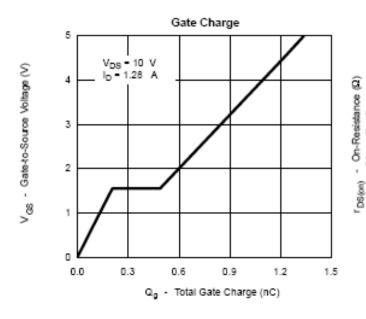


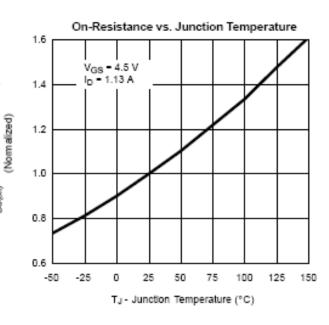


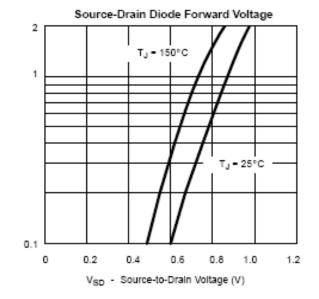




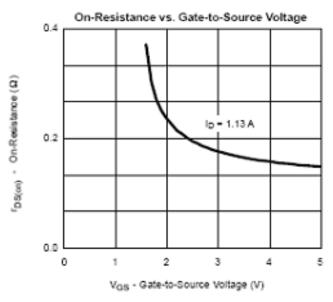
TYPICAL CHARACTERISTICS



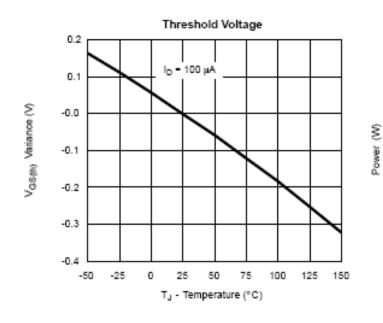


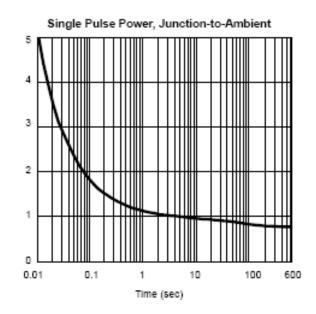


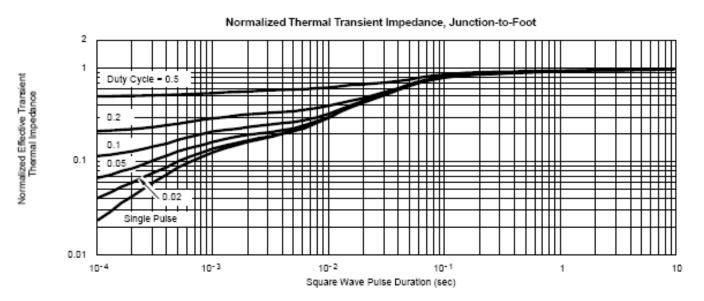
Is - Source Current (A)



TYPICAL CHARACTERISTICS







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